

Today, we would like to introduce SiC devices, which has higher efficiency by energy savings and is optimum for replacement from Si-IGBTs and Si-MOSs
SiC-MOSs significantly reduced power loss by 73% compared to Si-IGBTs.

ROHM is the first manufacturer in the world starting mass production of SiC MOS and our integrated production system realizes stable supply.

SiC introduce movie



More details:

http://micro.rohm.com/eu/special/vol_06/

If you need further information, please feel free to contact us.